

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	199	(gate adj metal adj region gate adj metal gate adj bus adj region termination near edge termination adj3 region)with(depression cavity recess)	US-PGPUB; USPAT	OR	ON	2005/08/19 16:32
L2	230	(gate adj metal adj region gate adj metal gate adj bus adj region termination near3 edge termination adj3 region)with(depression cavity recess)	US-PGPUB; USPAT	OR	ON	2005/08/19 16:28
L3	118689	(Trench\$1gat\$4 mos\$1gat\$3 mos mosfet field adj transistor\$2 gate near4 trench)	US-PGPUB; USPAT	OR	OFF	2005/08/19 16:30
L4	293923	(Trench\$1gat\$4 mos\$1gat\$3 mos mosfet field adj transistor\$2 gate near4 trench)	US-PGPUB; USPAT	OR	ON	2005/08/19 16:33
L5	50	2 and 4	US-PGPUB; USPAT	OR	ON	2005/08/19 16:36
L6	236	(gate adj metal adj region gate adj metal gate adj bus adj region termination near edge termination adj3 region)and(depression cavity recess)	EPO; JPO; DERWENT	OR	ON	2005/08/19 16:32
L7	189557	(Trench\$1gat\$4 mos\$1gat\$3 mos mosfet field adj transistor\$2 gate near4 trench)	EPO; JPO; DERWENT	OR	ON	2005/08/19 16:33
L8	10	6 and 7	EPO; JPO; DERWENT	OR	ON	2005/08/19 16:35
L9	4055	257/330-331 257/485-486 257/417 257/369 257/341 257/334.ccls.	US-PGPUB; USPAT	OR	OFF	2005/08/19 16:35
L10	7	2 and 9	US-PGPUB; USPAT	OR	OFF	2005/08/19 16:36
L11	2822	9 and 4	US-PGPUB; USPAT	OR	ON	2005/08/19 16:36
L12	92	11 and schottky and drift\$4 and (trench\$4 groov\$3)and (active channel\$2)	US-PGPUB; USPAT	OR	OFF	2005/08/19 16:38
L13	11	((termination terminating)adj (region))and 12	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:34
L14	4	((termination terminating)adj (region))same((control\$4) near8 (spread\$4 shap\$4)near7(electric adj field))	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:02

L15	16	("20020024081" "20020058381" "20020113263" "20030073271" "20040031987" "4262296" "4651184" "4661832" "5208657" "5231037" "5326711" "5610085" "6277751" "6316807" "6356059" "6673681").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/19 17:04
L16	3084	(257/302 257/288 257/328 257/3 30 257/332 257/E29.313.ccls.)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/19 17:05
L17	81	((termination terminating)adj (region))and 16	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:10
L18	636	((termination terminating)adj (region)).clm.	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:29
L19	217	4 and 18	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:10
L20	44	((((termination terminating)adj (region))same(gate)).clm.	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:32
L21	18	((((termination terminating)adj (region))same(Trench\$1gat\$4 mos\$1gat\$3 mos mosfet field adj transistor\$2 gate near4 trench)). clm.	US-PGPUB; USPAT	OR	OFF	2005/08/19 17:34
L22	457	((termination terminating)adj (region))	EPO; JPO; DERWENT	OR	ON	2005/08/19 17:34
L23	37210	(Trench\$1gat\$4 mos\$1gat\$3 mos mosfet field adj transistor\$2 gate near4 trench).ti.	EPO; JPO; DERWENT	OR	OFF	2005/08/19 17:34
L24	14	22 and 23	EPO; JPO; DERWENT	OR	OFF	2005/08/19 17:35